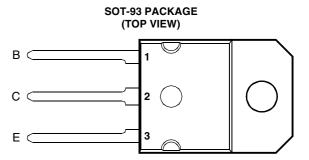
3OURNS®

- **Designed for Complementary Use with the BD745 Series**
- 115 W at 25°C Case Temperature
- 20 A Continuous Collector Current
- 25 A Peak Collector Current
- **Customer-Specified Selections Available**



Pin 2 is in electrical contact with the mounting base.

MDTRAAA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

| RATING | SYMBOL | VALUE | UNIT | |
|---|--------------------|------------------|-------------|----|
| | BD746 | | -50 | |
| Collector-base voltage (I _E = 0) | BD746A | V | -70 | V |
| | BD746B | V _{CBO} | -90 | V |
| | BD746C | | -110 | |
| | BD746 | | -45 | |
| Collector-emitter voltage (I _B = 0) | BD746A | V | -60 | V |
| | BD746B | V _{CEO} | -80 | V |
| | BD746C | | -100 | |
| Emitter-base voltage | V _{EBO} | -5 | V | |
| Continuous collector current | I _C | -20 | Α | |
| Peak collector current (see Note 1) | I _{CM} | -25 | Α | |
| Continuous base current | I _B | -7 | Α | |
| Continuous device dissipation at (or below) 25°C case temperature (see Note 2) | P _{tot} | 115 | W | |
| Continuous device dissipation at (or below) 25°C free air temperature (see Note | P _{tot} | 3.5 | W | |
| Unclamped inductive load energy (see Note 4) | | | 90 | mJ |
| Operating free air temperature range | | | -65 to +150 | °C |
| Operating junction temperature range | T _j | -65 to +150 | °C | |
| Storage temperature range | T _{stg} | -65 to +150 | °C | |
| Lead temperature 3.2 mm from case for 10 seconds | T _L 260 | | °C | |

- NOTES: 1. This value applies for $t_p \le 0.3$ ms, duty cycle $\le 10\%$. 2. Derate linearly to 150°C case temperature at the rate of 0.92 W/°C.
 - 3. Derate linearly to 150°C free air temperature at the rate of 28 mW/°C.
 - 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = -0.4 A, R_{BE} = 100 Ω , $V_{BE(off)} = 0$, $R_S = 0.1 \Omega$, $V_{CC} = -20 V$.



electrical characteristics at 25°C case temperature (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | | | MIN | TYP | MAX | UNIT |
|----------------------|---|--------------------------|-----------------------------|------------------------|------------------|-------------|-----|------|------|
| V/DD\0F0 | Collector-emitter breakdown voltage | I _C = -30 mA | I _B = 0 | (see Note 5) | BD746 BD746A | -45 -60 | | | V |
| | | | | | BD746B BD746C | -80 -100 | | | • |
| | | V _{CE} = -50 V | $V_{BF} = 0$ | | BD746 | | | -0.1 | |
| | | | $V_{BE} = 0$ | | BD746A | | | -0.1 | |
| | | $V_{CE} = -90 \text{ V}$ | | | BD746B | | | -0.1 | |
| | Collector cut-off | V _{CE} = -110 V | $V_{BE} = 0$ | | BD746C | | | -0.1 | |
| I _{CBO} | current | $V_{CE} = -50 \text{ V}$ | $V_{BE} = 0$ | $T_C = 125^{\circ}C$ | BD746 | | | -5 | mA |
| | | $V_{CE} = -70 \text{ V}$ | $V_{BE} = 0$ | T _C = 125°C | BD746A | | | -5 | |
| | | $V_{CE} = -90 \text{ V}$ | $V_{BE} = 0$ | T _C = 125°C | BD746B | | | -5 | |
| | | V _{CE} = -110 V | $V_{BE} = 0$ | T _C = 125°C | BD746C | | | -5 | |
| 1 | Collector cut-off | V _{CE} = -30 V | I _B = 0 | | BD746/746A | | | -0.1 | mA |
| ICEO | current | $V_{CE} = -60 \text{ V}$ | $I_B = 0$ | | BD746B/746C | | | -0.1 | MA |
| I _{EBO} | Emitter cut-off current | V _{EB} = -5 V | I _C = 0 | | | | | -0.5 | mA |
| | Forward current transfer ratio | V _{CE} = -4 V | I _C = -1 A | | | 40 | | | |
| h_{FE} | | V _{CE} = -4 V | $I_C = -5 A$ | (see Notes 5 and 6) | | 20 | | 150 | |
| | | V _{CE} = -4 V | $I_{\rm C} = -20 \ {\rm A}$ | | | 5 | | | |
| V | Collector-emitter | $I_B = -0.5 A$ | I _C = -5 A | (see Notes 5 and 6) | | | | -1 | V |
| V _{CE(sat)} | saturation voltage | I _B = -5 A | | | | | | -3 | v |
| V _{BE} | Base-emitter | V _{CE} = -4 V | - | (see Notes 5 and 6) | | | | -1 | V |
| v BE | voltage | $V_{CE} = -4 V$ | $I_{\rm C} = -20 \text{A}$ | | | | | -3 | |
| h _{fe} | Small signal forward | V _{CF} = -10 V | I _C = -1 A | | f = 1 kHz | 25 | | | |
| 16 | current transfer ratio | - C | | | | | | | |
| h _{fe} | Small signal forward current transfer ratio | V _{CE} = -10 V | $I_C = -1 A$ | | f = 1 MHz | 5 | | | |

NOTES: 5. These parameters must be measured using pulse techniques, $t_p = 300 \mu s$, duty cycle $\leq 2\%$.

thermal characteristics

| PARAMETER | | | TYP | MAX | UNIT |
|-----------------|---|--|-----|------|------|
| $R_{\theta JC}$ | Junction to case thermal resistance | | | 1.1 | °C/W |
| $R_{\theta JA}$ | Junction to free air thermal resistance | | | 35.7 | °C/W |

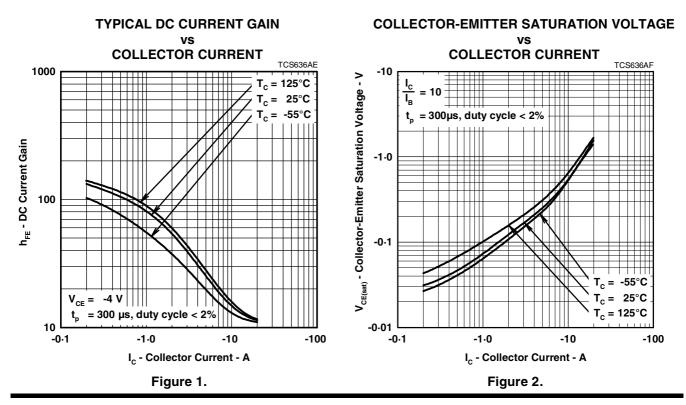
resistive-load-switching characteristics at 25°C case temperature

| | PARAMETER | TEST CONDITIONS † | | | MIN | TYP | MAX | UNIT |
|----------------|--------------|-----------------------|----------------------|------------------------------|-----|-----|-----|------|
| t _d | Delay time | | | | | 20 | | ns |
| t _r | Rise time | I _C = -5 A | $I_{B(on)} = -0.5 A$ | $I_{B(off)} = 0.5 A$ | | 120 | | ns |
| t _s | Storage time | $V_{BE(off)} = 4.2 V$ | $R_L = 6 \Omega$ | $t_p = 20 \mu s, dc \le 2\%$ | | 600 | | ns |
| t _f | Fall time | | | | | 300 | | ns |

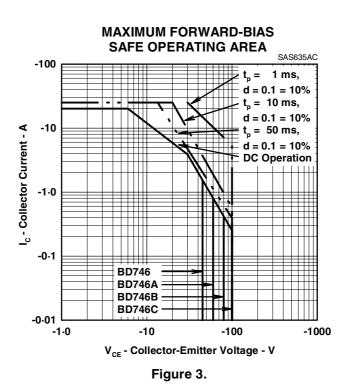
[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

^{6.} These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

TYPICAL CHARACTERISTICS



MAXIMUM SAFE OPERATING REGIONS



PRODUCT INFORMATION

THERMAL INFORMATION

MAXIMUM POWER DISSIPATION

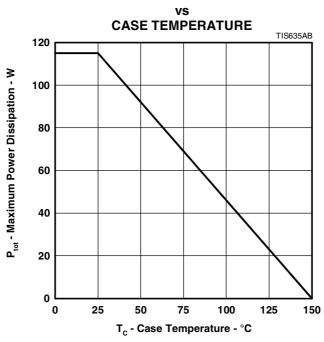


Figure 4.